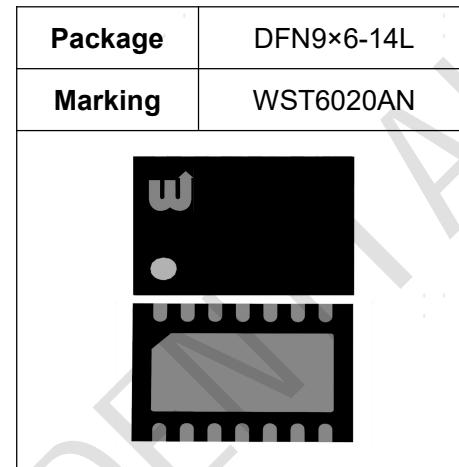


WST6020AN**Smart High-Side Power Switch Single Channel, 20mΩ, DFN9×6-14L , AEC-Q100 qualified****Application**

- ◆ Suitable for resistive, inductive and capacitive loads
- ◆ Replaces electromechanical relays, fuses and discrete circuits
- ◆ Most suitable for loads with high inrush current, such as lamps
- ◆ Suitable for 12 V and 24 V trucks + trailer and transportation systems

Basic Features

- ◆ Single channel device
- ◆ Very low stand-by current
- ◆ 3.3 V and 5 V compatible logic inputs
- ◆ Optimized electromagnetic compatibility
- ◆ Very low electromagnetic susceptibility

**Product Summary**

Parameter	Symbol	Value
Max. transient supply voltage	V_S	60V
Operating voltage range	V_{NOM}	8-36V
On-state resistance ($T_j = 25^\circ C$)	R_{ON}	20mΩ
Nominal load current ($T_j = 25^\circ C$)	$I_{L(NOM)}$	9A
Typical current sense ratio ($I_{OUT}=4A$)	K	3160
Current limitation	I_{LIMH}	30A
Supply current in sleep	I_{SLEEP}	3uA

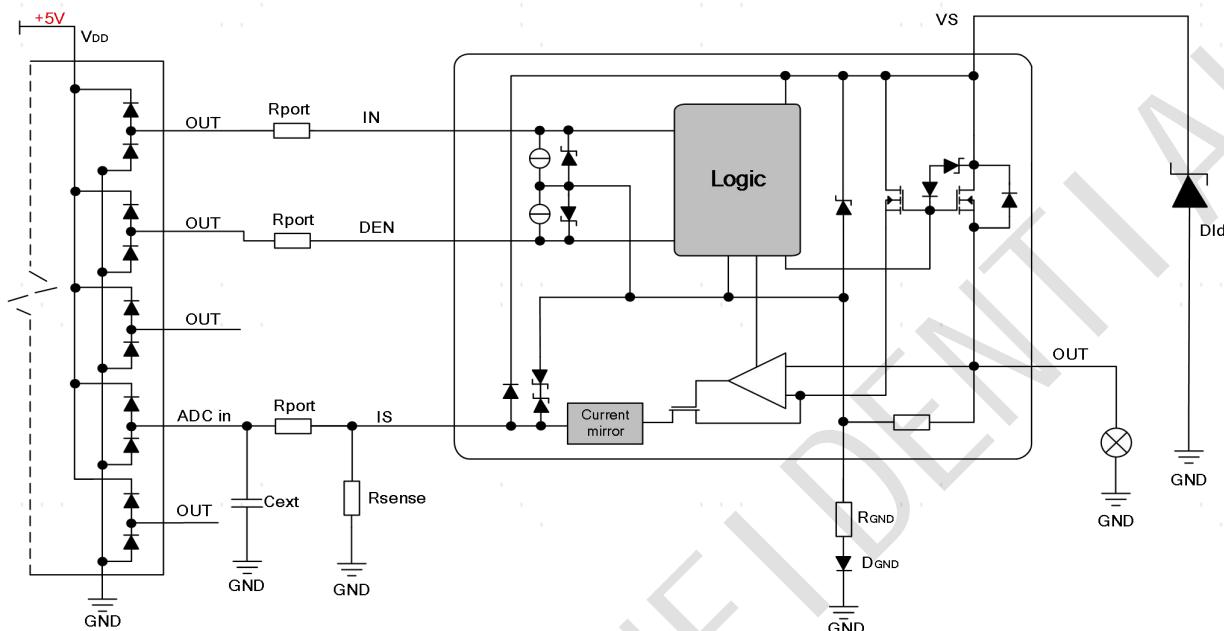
Diagnostic Functions

- ◆ Proportional load current sense
- ◆ High current sense precision for wide range currents
- ◆ Off-state open load detection
- ◆ OUT short to VS detection
- ◆ Overload and short to ground latch-off
- ◆ Thermal shutdown latch-off
- ◆ Very low current sense leakage

Protection Functions

- ◆ Undervoltage shutdown
- ◆ Overvoltage clamp
- ◆ Load current limitation
- ◆ Self limiting of fast thermal transients
- ◆ Protection against loss of ground and loss of VS
- ◆ Thermal shutdown
- ◆ Electrostatic discharge protection

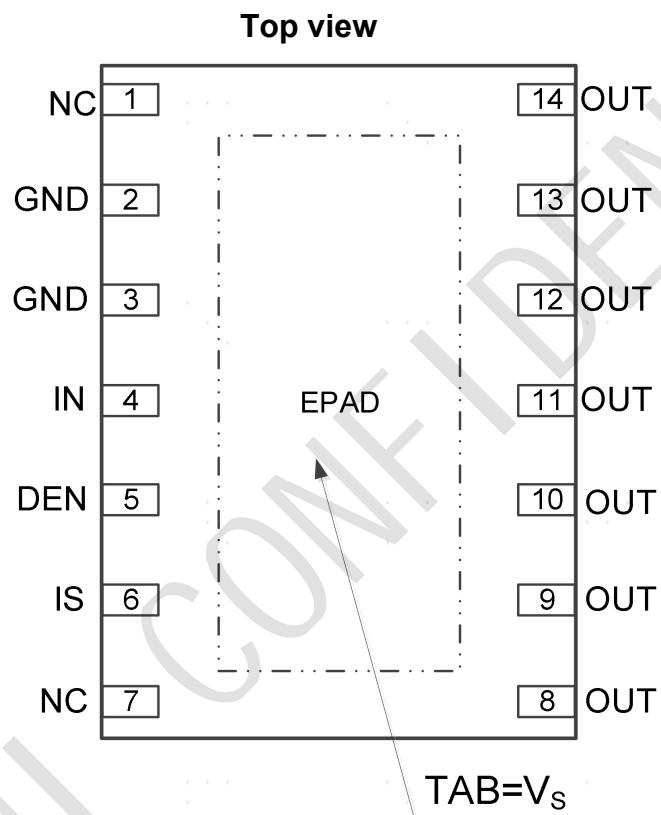
Typical Application Circuit



Ordering Information

Package	Top Mark	Part No.
DFN9×6-14L, Pb-free	WST6020AN XXYMXX	WST6020AN

Pin Configuration



Pin Description

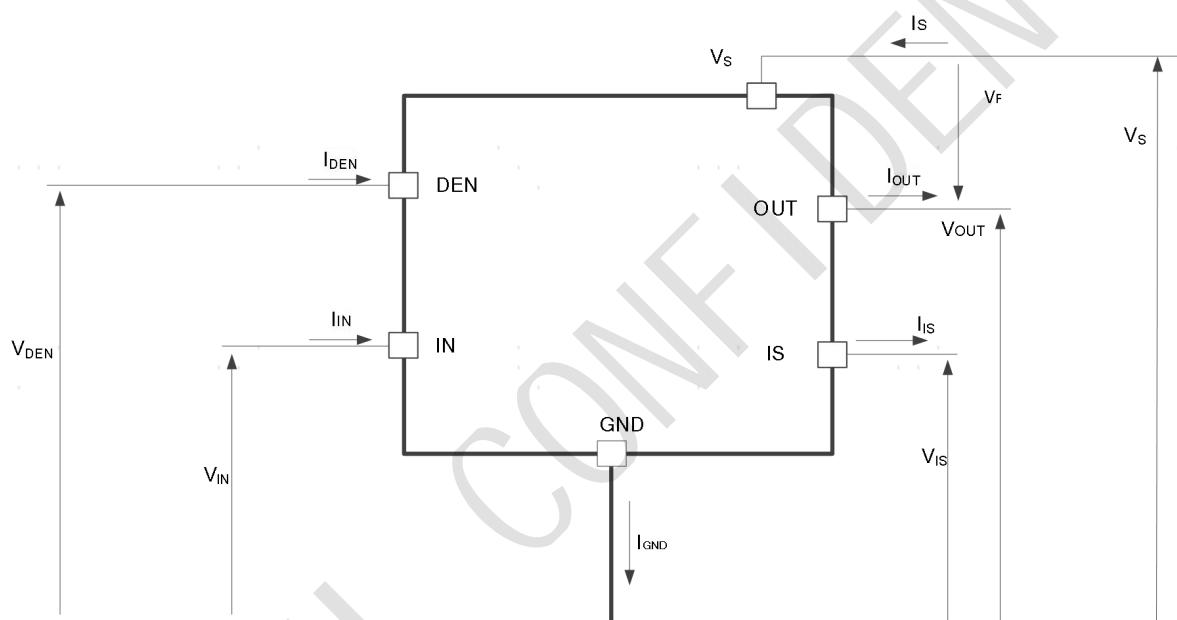
Pin Name	Pin NO.	Pin Description
NC	1/7	Not Connected
GND	2/3	Ground connection. Must be reverse battery protected by an external diode / resistor network.
IN	4	Voltage controlled input pin with hysteresis, compatible with 3 V and 5 V CMOS outputs. It controls output switch state.
DEN	5	Active high compatible with 3 V and 5 V CMOS outputs pin; it enables the IS diagnostic pin.
IS	6	Multiplexed analog sense output pin; it delivers a current proportional to the selected diagnostic:
OUT	8/9/10/11/12/13/14	Power outputs.
VS	EPAD	Battery connection.

Table 1. Suggested connections for unused and not connected pins

Connection / pin	IS	OUT	IN	DEN
Floating	Not allowed	X ⁽¹⁾	X	X
To ground	Through 1.0K resistor	Not allowed	Through 15K resistor	Through 15K resistor

Note1: X do not care.

Current and Voltage Conventions

Note2: $V_F = V_{OUT} - V_S$ during reverse battery condition.

Absolute Maximum Ratings (Note3)

Symbol	Parameter	Value	Unit
V_s	DC supply voltage	60	V
$-V_s$	Reverse DC supply voltage	0.3	V
$-I_{GND}$	DC reverse ground pin current	200	mA
I_{OUT}	OUT DC output current	Internally limited	A
V_{IN}, V_{DEN}, V_{CL}	IN, DEN DC input voltage	-0.3 to 6.0	V
I_{IS}	IS pin DC output current	20	mA
	IS pin DC output current in reverse	-20	
T_j	Junction operating temperature	-40 to 150	°C
T_{stg}	Storage temperature	-55 to 150	

Note3: Stressing the device above the rating listed in Absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied.

Exposure to the conditions in table below for extended periods may affect device reliability.

Thermal Resistance (Note4)

Symbol	Parameter	Value	Unit
T_{JC}	Thermal Resistance Junction-to-Case	1.3	°C/W
T_{JA}	Junction-to-Ambient Thermal Resistance	30	°C/W

Note4: According to JEDEC JESD51-2,-5,-7 at natural convection on FR4 2s2p board; the Product (Chip + Package) was simulated on a 76.2 × 114.3 × 1.5 mm board with 2 inner copper layers (2 × 70 µm Cu, 2 × 35 µm Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

ESD Susceptibility (Note5)

Symbol	Parameter	Values	Unit
$V_{ESD(HBM)}^3)$	ESD Susceptibility all Pins (HBM)	± 2	kV
$V_{ESD(HBM)_OUT}$	ESD Susceptibility OUT vs GND and Vs connected (HBM)	± 4	kV
$V_{ESD(CDM)}^4)$	ESD Susceptibility all Pins (CDM)	± 500	V
$V_{ESD(CDM)_{CRN}}$	ESD Susceptibility Corner Pins (CDM) (pins 1, 7, 8, 14)	± 750	V

Note5:

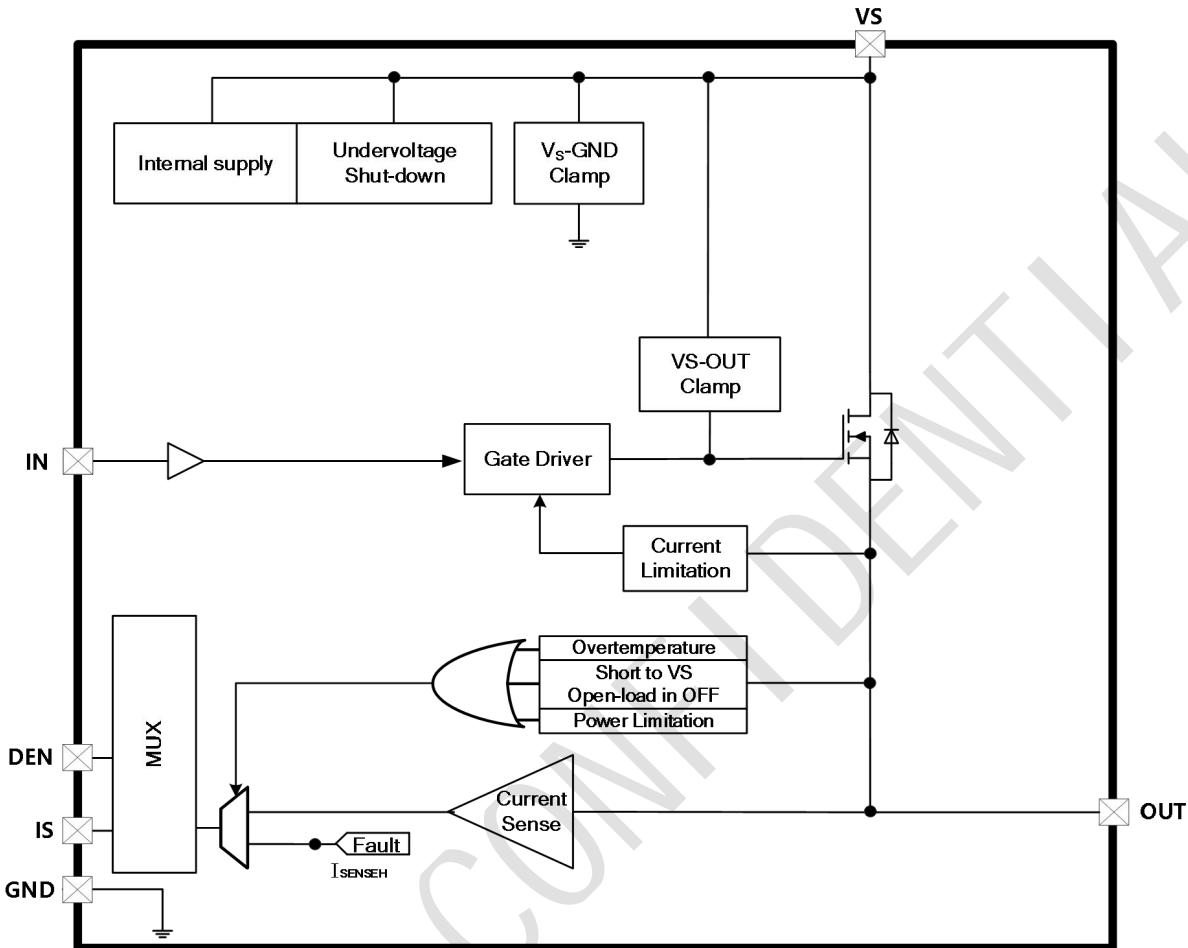
- 1) Not subject to production test - specified by design.
- 2) Maximum digital input voltage to be considered for Latch-Up tests: 5.5 V.
- 3) ESD susceptibility, Human Body Model "HBM", according to AEC Q100-002.
- 4) ESD susceptibility, Charged Device Model "CDM", according to AEC Q100-011.

EAS Susceptibility (Note6)

Symbol	Parameter	Values			Unit	Note or Test Condition
		Min.	Typ.	Max.		
E_{AS}	Maximum Energy Dissipation Single Pulse			230	mJ	$I_{OUT} = 9A$ $T_{J(0)} = 150 \text{ }^\circ\text{C}$ $V_S = 28 \text{ V}$

Note6: Not subject to production test - specified by design.

Functional Block



Electrical Characteristics (Note⁷) , 8V<Vs < 36 V; -40°C < Tj < 150°C, unless otherwise specified**Power section**

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Nominal operating voltage	V _{NOM}		8	24	36	V
Extended operating voltage	V _{OP}		5		58	V
Under voltage shutdown	V _{USD}			3.5	5.0	V
Under voltage shutdown hysteresis	V _{USDhyst}			0.3		V
On-state resistance	R _{ON}	I _{OUT} =5A, T _j = 25°C		20		mΩ
		I _{OUT} =5A, T _j = 150°C			40	
		I _{OUT} =5A, V _S =5V, T _j = 25°C			32	
Nominal load current	I _{L(NOM)}	T _A =25°C		9		A
Nominal load current at T _A =85°C	I _{L(NOM)_85}	T _A =85°C, T _j < 150°C		7		A
Inverse Current Capability	I _{L(INV)}	V _S <V _{OUT} , V _{IN} =5V, T _A =25°C		9		A
V _S clamp voltage	V _{CLAMP}	I _S =20 mA	60	64	71	V
Supply current in sleep	I _{SLEEP}	V _S =36V, V _{IN} =V _{OUT} =V _{DEN} =0V, T _j =25°C		3.0	6.0	µA
		V _S =36V, V _{IN} =V _{OUT} =V _{DEN} =0V, T _j = 125°C			20	µA
Sleepy mode blanking time	t _{D_SLEEP}	V _S =36V, V _{IN} =V _{OUT} =0V V _{DEN} =5V to 0V	150	400	800	us
Supply current in active	I _{S(ACTIVE)}	V _S =36V, V _{DEN} =5V, V _{IN} =0V,		2.0	4.0	mA
Control stage current consumption in ON state	I _{GND(ON)}	V _S =36V, V _{DEN} =5V, V _{IN} =5V		8.0	16	mA
Off-state output current	I _{L(off)}	V _{IN} =V _{OUT} =0V, V _S =36V, T _j =25°C	0	0.1	3	µA
		V _{IN} =V _{OUT} =0V, V _S =36V, T _j =125°C	0		6	µA
OUT - V _S diode voltage	V _F	I _{OUT} =-2A, T _j =150°C			0.9	V

Switching

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Turn-on delay time at T _j = 25°C	T _{d(on)}	V _S =28V,V _{DEN} =5V,R _L =6.5Ω	-	15	90	us
Turn-off delay time at T _j = 25°C	T _{d(off)}		-	28	100	us
Turn-on voltage slope at T _j = 25°C	(dV _{OUT} /dt) _{on}	V _S =28V,V _{DEN} =5V,R _L =6.5Ω	0.2	0.5	1.5	V/us
Turn-off voltage slope at T _j = 25°C	(dV _{OUT} /dt) _{off}		0.5	1.0	2.5	
Differential pulse skew(t _{PHL} - t _{PLH})	t _{SKew}	V _S =28V,V _{DEN} =5V,R _L =6.5Ω	-50	-	50	us

Logic input (IN, DEN)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Logic input low level voltage	V _{LOW}				0.9	V
Low level logic input current	I _{LOW}	V _{LOW} =0.9V	2	11	35	uA

WST6020AN Product Description

High-side driver with current sense analog feedback for 24V automotive applications



Logic input high level voltage	V _{HIGH}		2.1		6.0	V
High level logic input current	I _{HIGH}	V _{HIGH} =2.0V	1	10	32	uA
Logic input hysteresis voltage	V _(hyst)		-	0.2	-	V

Protections

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
DC short circuit current	I _{LIMH}	5V < V _S < 36V, V _{DS} =6V	20	30	40	A
		V _{DS} =32V		15		
Short circuit current during thermal cycling	I _{LIML}	V _S =24V, V _{DEN} =5V, T _R <T _j <T _{TSD}		12		
Maximum number of Short mode latch				5		cycles
Shutdown temperature	T _{TSD}		150	175	200	°C
Thermal hysteresis	T _{HYST}			20		°C
Current limit reset temperature	T _R			135		°C
Dynamic temperature	ΔT _{J_SD}	T _j = -40°C		60		°C
Turn-off output voltage clamp	V _{DEMAG}	I _{OUT} =2A, V _{DEN} =5V, L= 6mH, T _j = -40°C to 150°C	V _S -60	V _S -64	V _S -71	V

Current sense characteristics

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
I _{OUT} /I _S	K ₀	I _{OUT} =50mA, V _{DEN} =5V	-15%	1200	+15%	
I _{OUT} /I _S	K ₁	I _{OUT} =0.5A, V _{DEN} =5V	-8%	2750	+8%	
I _{OUT} /I _S	K ₂	I _{OUT} =2A, V _{DEN} =5V	-4%	3090	+4%	
I _{OUT} /I _S	K ₃	I _{OUT} =4A, V _{DEN} =5V	-3.5%	3160	+3.5%	
I _{OUT} /I _S	K ₄	I _{OUT} =7A, V _{DEN} =5V	-3.5%	3200	+3.5%	
Current sense leakage current	I _{IS0}	CS disabled: V _{DEN} = 0V	0		1	uA
		CS enabled: V _{DEN} = 5V, I _{OUT} = 0A		25		
Output voltage for IS shutdown	V _{OUT_MSD}	V _{DEN} =5V, R _{SENSE} =3.9K, V _{IN} =5V; I _{OUT} =5A		5		V
Max analog sense output voltage	V _{IS}	V _S =28V, V _{IS} =5V	4.5			V
Current sense output current in fault condition	I _{ISH}	V _S =28V, V _{IS} =5V	10	20	30	mA
Current sense output voltage in fault condition	V _{ISH}	V _S =28V, V _{IS} =5V	5.4	6	6.6	V

OFF-state diagnostic

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
OFF-state open load voltage detection threshold (VS-OUT)	V _{OL}	V _{DEN} =5V, V _{IN} =0V	4	5	6	V
OFF-state output sink current	I _{L(off2)}	V _S =28V, V _{IN} = 0V, V _{OUT} =28V-V _{OL} , T _j = -40°C to 150°C	-2	-1.4	-0.5	mA
OFF-state diagnostic delay time from falling edge of IN	t _{DSTKON}	V _{DEN} =5V, V _{OUT} =V _S , V _{IN} = 5V to 0V	150	400	800	us

WST6020AN Product Description

High-side driver with current sense analog feedback for 24V automotive applications



Settling time for valid OFF-state open load diagnostic indication from rising edge of DEN	$t_{D_OL_V}$	$V_{IN}=0V, V_{OUT}=V_S, V_{DEN}=0V \text{ to } 5V$			150	us
OFF-state diagnostic delay time from rising edge of V_{OUT}	t_{D_VOL}	$V_{DEN}=5V, V_{IN}=0V, V_{OUT}=V_S-6V \text{ to } V_S$		5	30	us

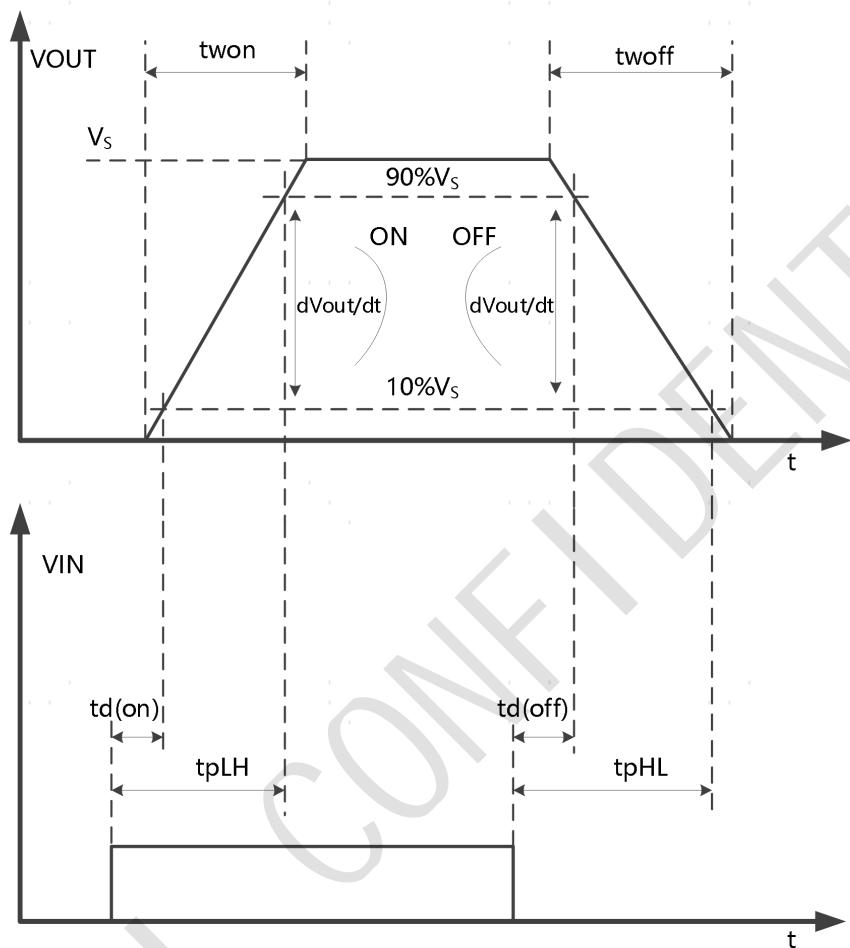
Current sense timings

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Current sense settling time from rising edge of DEN	$t_{DSENSE1H}$	$V_{IN}=5V, V_{DEN}=0V \text{ to } 5V, R_{SENSE}=1K, R_L=6.5\Omega$			100	us
Current sense disable delay time from falling edge of DEN	$t_{DSENSE1L}$	$V_{IN}=5V, V_{DEN}=5V \text{ to } 0V, R_{SENSE}=1K, R_L=6.5\Omega$		5	20	us
Current sense settling time from rising edge of IN	$t_{DSENSE2H}$	$V_{IN}=0V \text{ to } 5V, V_{DEN}=5V, R_{SENSE}=1K, R_L=6.5\Omega$		80	250	us
Current sense settling time from rising edge of I_{OUT} (dynamic response to a step change of I_{OUT})	$\Delta t_{DSENSE2H}$	$V_{IN}=5V, V_{DEN}=5V, R_{SENSE}=1K, I_{IS}=90\% \text{ of } I_{IS_MAX}, I_{OUT} = 90\% \text{ of } I_{OUTMAX}, R_L=6.5\Omega$			150	us
Current sense turn-off delay time from falling edge of IN	$t_{DSENSE2L}$	$V_{IN}=5V \text{ to } 0V, V_{DEN}=5V, R_{SENSE}=1K, R_L=6.5\Omega$		80	250	us

Note7: Except for the special test instructions, all electrical parameters are tested under $T_A = +25^\circ C$. The minimum and maximum specification range of the specifications is guaranteed by the test, and the typical values are guaranteed by the design, test, or statistical analysis.

Switching Status and Timing Relationship

Switching time and pulse skew



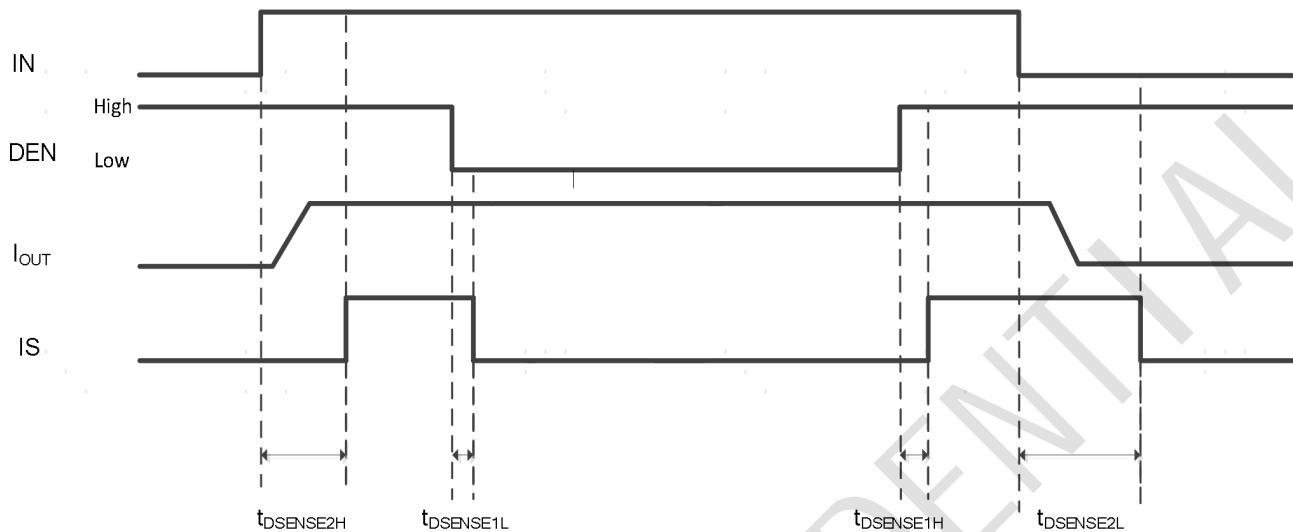
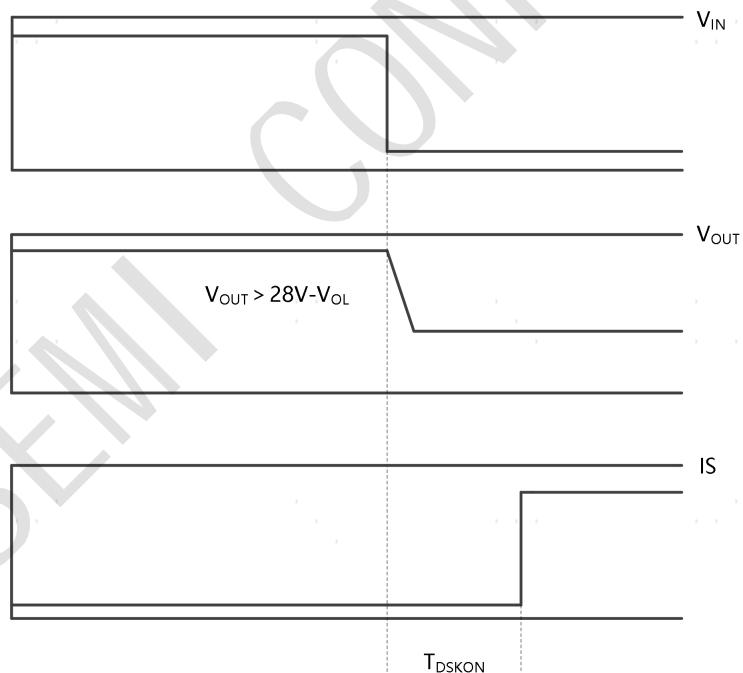
Current sense timings (current sense mode)**T_{DSKON}**

Table 2. Truth table

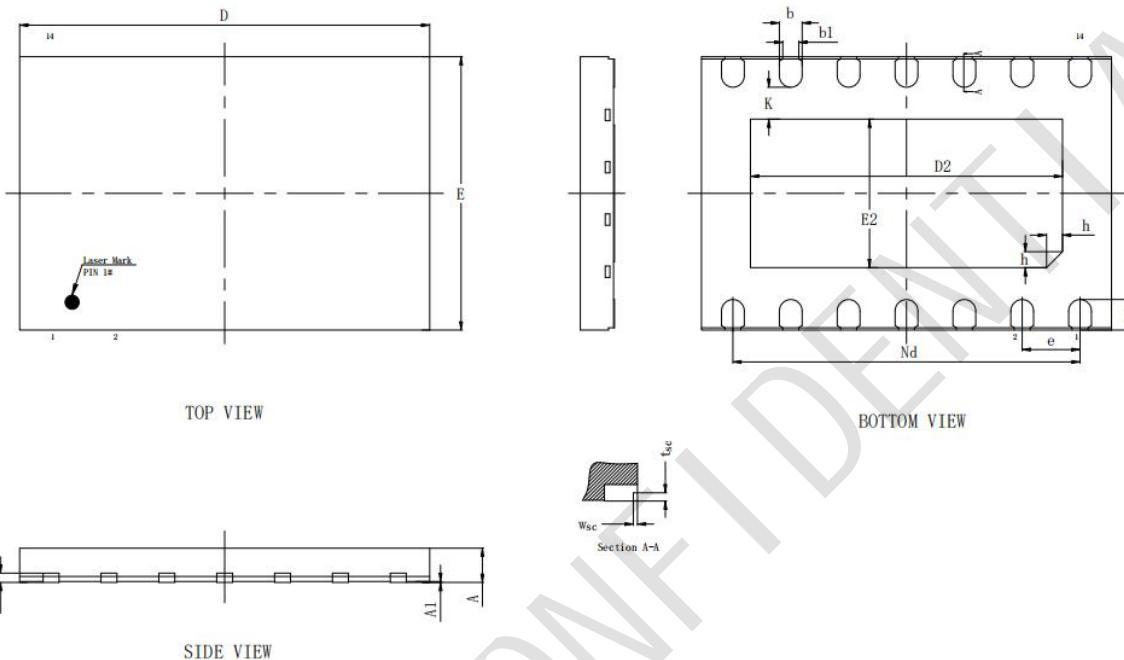
Conditions	IN	DEN	OUT	IS
Standby	L	L	L	0
Normal	L	H	L	0
	H	H	H	$I_{IS} = I_{OUT}/K$
Overload	H	H	H	I_{ISH}
OverTemperature	L	H	L	0
	H	H	H	I_{ISH}
Undervoltage	X	X	L	0
Short to V_S	L	H	H	I_{ISH}
	H	H	H	<Normal
Open-Load	L	H	H	I_{ISH}
Short circuit to GND	H	H	L	I_{ISH}

Table 3. Current sense output

DEN	MUX Channel	Current sense output			
		Normal	Overload	OFF-state	Negative output
L			Hi-Z		
H	Channel diagnostic	$I_{IS} = I_{OUT}/K$	$I_{IS} = I_{ISH}$	$I_{IS} = I_{ISH}$	Hi-Z

Package Outline

DFN9×6-14L



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0	0.02	0.05
b	0.45	0.50	0.55
b1	0.35REF		
c	0.203REF		
D	8.90	9.00	9.10
D2	6.75	6.85	6.95
e	1.27BSC		
Nd	7.62BSC		
E	5.90	6.00	6.10
E2	3.16	3.26	3.36
L	0.62	0.67	0.72
h	0.30	0.35	0.40
K	0.70REF		
W _{sc}	0.01	-	0.09
t _{sc}	0.08	-	0.18

WST6020AN Product Description

High-side driver with current sense analog feedback for 24V automotive applications



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